National Semiconductor

LM112/LM212/LM312 Operational Amplifiers

General Description

The LM112 series are micropower operational amplifiers with very low offset-voltage and input-current errors—at least a factor of ten better than FET amplifiers over a -55° C to $+125^{\circ}$ C temperature range. Similar to the LM108 series, that also use supergain transistors, they differ in that they include internal frequency compensation and have provisions for offset adjustment with a single potentiometer.

These amplifiers will operate on supply voltages of $\pm 2V$ to $\pm 20V$, drawing a quiescent current of only 300 μ A. Performance is not appreciably affected over this range of voltages, so operation from unregulated power sources is easily accomplished. They can also be run from a single supply like the 5V used for digital circuits.

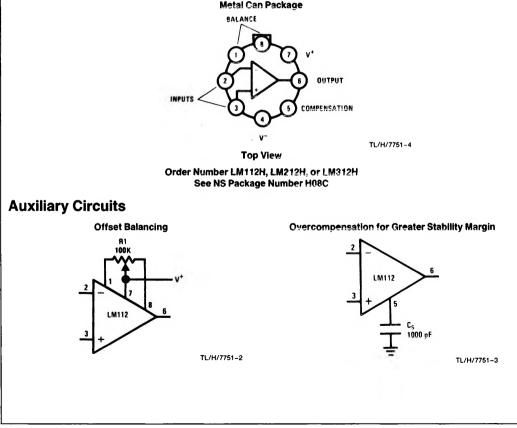
The LM112 series are the first IC amplifiers to improve reliability by including overvoltage protection for the MOS compensation capacitor. Without this feature, IC's have been known to suffer catastrophic failure caused by short-duration overvoltage spikes on the supplies. Unlike other internally-compensated IC amplifiers, it is possible to overcompensate with an external capacitor to increase stability margin.

The LM212 is identical to the LM112, except that the LM212 has its performance guaranteed over a -25° C to $+85^{\circ}$ C temperature range instead of -55° C to $+125^{\circ}$ C. The LM312 is guaranteed over a 0°C to $+70^{\circ}$ C temperature range.

Features

- Maximum input bias current of 3 nA over temperature
- Offset current less than 400 pA over temperature
- Low noise
- Guaranteed drift specifications





Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications. (Note 5)

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	LM112/LM212	LM312
Supply Voltage	±20V	±18V
Power Dissipation (Note 1)	500 mW	500 mW
Differential Input Current (Note 2)	±10 mA	± 10 mA
Input Voltage (Note 3)	±15V	±15V
Output Short-Circuit Duration	Continuous	Continuous
Operating Temperature Range LM112 LM212	−55°C to +125°C −25°C to +85°C	0°C to +70°C
Storage Temperature Range	-65°C to +150°C	-65°C to +150°C
Lead Temperature (Soldering, 10 sec.) ESD rating to be determined.	300°C	300°C

Electrical Characteristics (Note 4)

Parameter	Conditions	LM1	112/LM212		LM312			Units
	Conditions	Min	Тур	Max	Min	Тур	Max	
Input Offset Voltage	T _A = 25°C		0.7	2.0		2.0	7.5	mV
Input Offset Current	T _A = 25°C		0.05	0.2		0.2	1	nA
Input Bias Current	T _A = 25°C		0.8	2.0		1.5	7	nA
Input Resistance	T _A = 25°C	30	70		10	40		MΩ
Supply Current	$T_A = 25^{\circ}C$		0.3	0.6		0.3	0.8	mA
Large Signal Voltage Gain	$\begin{array}{l} T_{A}=25^{\circ}C, V_{S}=\pm15V\\ V_{OUT}=\pm10V, R_{L}\geq10\ k\Omega \end{array}$	50	300		25	300		V/mV
Input Offset Voltage				3.0			10	mV
Average Temperature Coefficient of Input Offset Voltage			3.0	15		6.0	30	μV/°C
Input Offset Current				0.4			1.5	nA
Average Temperature Coefficient of Input Offset Current			0.5	2.5		2.0	10	pA/°C
Input Bias Current				3.0			10	nA
Supply Current	T _A = 125°C		0.15	0.4				mA
Large Signal Voltage Gain	$\label{eq:VS} \begin{array}{l} V_S = \ \pm \ 15 V, V_{OUT} = \ \pm \ 10 V \\ R_L \geq \ 10 \ k \Omega \end{array}$	25			15			V/mV
Output Voltage Swing	$V_{S} = \pm 15 V, R_{L} = 10 k\Omega$	±13	±14		±13	±14		v
Input Voltage Range	$V_{\rm S} = \pm 15V$	±13.5			±14			v
Common-Mode Rejection Ratio		85	100		80	100		dB
Supply Voltage Rejection Ratio		80	96		80	96		dB

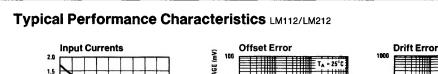
Note 1: The maximum junction temperature of the LM112 is 150°C, LM212 is 100°C and LM312 is 85°C. For operating at elevated temperatures, devices in the H08 package must be derated based on a thermal resistance of 160°C/W, junction to ambient, or 20°C/W, junction to case.

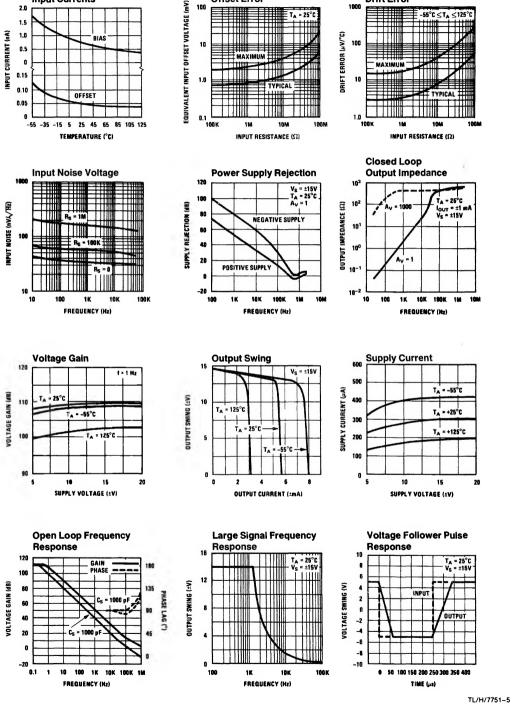
Note 2: The inputs are shunted with shunt diodes for overvoltage protection. Therefore, excessive current will flow if a differential input voltage in excess of 1V is applied between the inputs unless some limiting resistance is used.

Note 3: For supply voltages less than \pm 15V, the absolute maximum input voltage is equal to the supply voltage.

Note 4: These specifications apply for $\pm 5V \le V_S \le \pm 20V$ and $-55^{\circ}C \le T_A \le +125^{\circ}C$ (LM112), $-25^{\circ}C \le T_A \le +85^{\circ}C$ (LM212), $\pm 5V \le V_S \le \pm 15V$ and $0^{\circ}C \le T_A \le +70^{\circ}C$ (LM312) unless otherwise noted.

Note 5: Refer to RETS112X for LM112H military specifications.





-55°C ≤T_A ≤125°C

LM112/LM212/LM312

